



Design Example Report

| | |
|------------------------|---|
| Title | <i>17W (25W peak) DVD Recorder Power Supply using TOP245P</i> |
| Specification | Input: 90 – 265 VAC Output: 3.4V/2.55A, 5.1V/1.5A, 5.1Vsb/0.85A, 12V/2.8A, 12Vsb/0.4A, -5.3V/0.3A, -5.3Vsb/20mA, -22Vsb/10mA, +33Vsb/2mA, 3.5V VFD/165mA |
| Application | DVD Recorder |
| Author | Power Integrations Applications Department |
| Document Number | DER-18 |
| Date | March 30, 2004 |
| Revision | 1.0 |

Summary and Features

This report describes a design for a DVD power supply, featuring the following:

- No heatsinks
- Switched Outputs for Low Standby consumption
- Low cost/ Low parts count
- No Y-cap
- No X-cap
- Meets EMI requirements

The products and applications illustrated herein (including circuits external to the products and transformer construction) may be covered by one or more U.S. and foreign patents or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com.

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Important Note:

Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.

Design Reports contain a power supply design specification, schematic, bill of materials, and transformer documentation. Performance data and typical operation characteristics are included. Typically only a single prototype has been built.



1 Introduction

This document is an engineering report describing a prototype multiple output power supply utilizing a TOP245P. This power supply is designed for a DVD Recorder or similar application.

This design is low cost and meets EMI with no X-cap, and no Y-cap. It meets thermal requirements with no heatsink in either primary or secondary side.

The document contains the power supply specification, schematic, bill of materials, transformer documentation, printed circuit layout, and performance data.

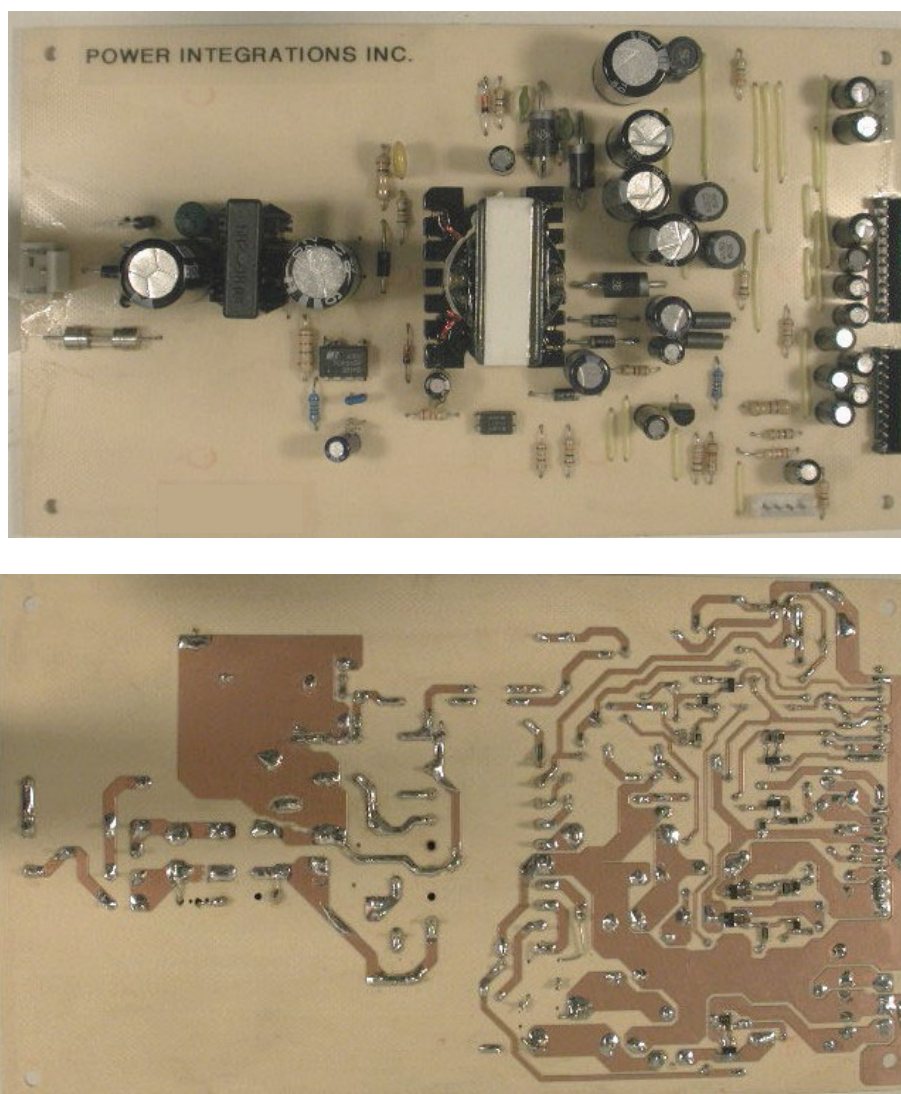


Figure 1 – Populated Circuit Board Photograph. Component side (Top) and Solder side (Bottom).

2 Power Supply Specification

| Description | Symbol | Min | Typ | Max | Units | Comment |
|-------------------------------|----------------|-------|-------|-------|-------|---|
| Input | | | | | | |
| Voltage | V_{IN} | 85 | | 280 | VAC | |
| Frequency | f_{LINE} | 47 | 50/60 | 64 | Hz | |
| No-load Input Power (230 VAC) | | | | N/A | W | |
| Output | | | | | | |
| Output Voltage 1 | V_{OUT1} | 3.3 | 3.4 | 3.5 | V | |
| Output Ripple Voltage 1 | $V_{RIPPLE1}$ | | | 50 | mV | 20 MHz Bandwidth |
| Output Current 1 | I_{OUT1} | | | 2.55 | A | |
| Output Voltage 2 | V_{OUT2} | 4.85 | 5.1 | 5.25 | V | |
| Output Ripple Voltage 2 | $V_{RIPPLE2}$ | | | 50 | mV | 20 MHz Bandwidth |
| Output Current 2 | I_{OUT2} | | | 1.5 | A | |
| Output Voltage 3 | V_{OUT3} | 4.94 | 5.1 | 5.46 | V | Standby Output |
| Output Ripple Voltage 3 | $V_{RIPPLE3}$ | | | 100 | mV | 20 MHz Bandwidth |
| Output Current 3 | I_{OUT3} | .08 | | 0.85 | A | |
| Output Voltage 4 | V_{OUT4} | 10.8 | 12.0 | 12.8 | V | |
| Output Ripple Voltage 4 | $V_{RIPPLE4}$ | | | 100 | mV | 20 MHz Bandwidth |
| Output Current 4 | I_{OUT4} | 0 | | 2.8 | A | |
| Output Voltage 5 | V_{OUT5} | 11.4 | 12.0 | 12.8 | V | Standby Output |
| Output Ripple Voltage 5 | $V_{RIPPLE5}$ | | | 100 | mV | 20 MHz Bandwidth |
| Output Current 5 | I_{OUT5} | 0.14 | | 0.4 | A | |
| Output Voltage 6 | V_{OUT6} | -5.5 | -5.3 | -5.0 | V | |
| Output Ripple Voltage 6 | $V_{RIPPLE6}$ | | | 50 | mV | 20 MHz Bandwidth |
| Output Current 6 | I_{OUT6} | 0 | | 0.3 | A | |
| Output Voltage 7 | V_{OUT7} | -5.5 | -5.3 | -5.0 | V | Standby Output |
| Output Ripple Voltage 7 | $V_{RIPPLE7}$ | | | 200 | mV | 20 MHz Bandwidth |
| Output Current 7 | I_{OUT7} | 0 | | 0.02 | A | |
| Output Voltage 8 | V_{OUT8} | 30 | 33 | 35 | V | Standby Output |
| Output Ripple Voltage 8 | $V_{RIPPLE8}$ | | | 50 | mV | 20 MHz Bandwidth |
| Output Current 8 | I_{OUT8} | 0.001 | | 0.002 | A | |
| Output Voltage 8 | V_{OUT8} | -28 | -22 | -18 | V | Standby Output |
| Output Ripple Voltage 8 | $V_{RIPPLE8}$ | | | 50 | mV | 20 MHz Bandwidth |
| Output Current 8 | I_{OUT8} | | | 0.010 | A | |
| Output Voltage 8 | V_{OUT8} | 3.15 | 3.5 | 3.85 | V | Filament Power Floating Winding |
| Output Ripple Voltage 8 | $V_{RIPPLE8}$ | | | 50 | mV | 20 MHz Bandwidth |
| Output Current 8 | I_{OUT8} | | | 0.165 | A | |
| Total Output Power | | | | | | |
| Continuous Output Power | P_{OUT} | | 17 | | W | |
| Peak Output Power | $P_{OUT PEAK}$ | | 25 | | W | |
| Efficiency | η | 74 | | | % | Measured at P_{OUT} (17 W), 25 °C |
| Environmental | | | | | | |
| Conducted EMI | | | | | | Meets CISPR22B / EN55022B |
| Safety | | | | | | Designed to meet IEC950, UL1950 Class II |
| Ambient Temperature | T_{AMB} | | 25 | | °C | Free convection, sea level |



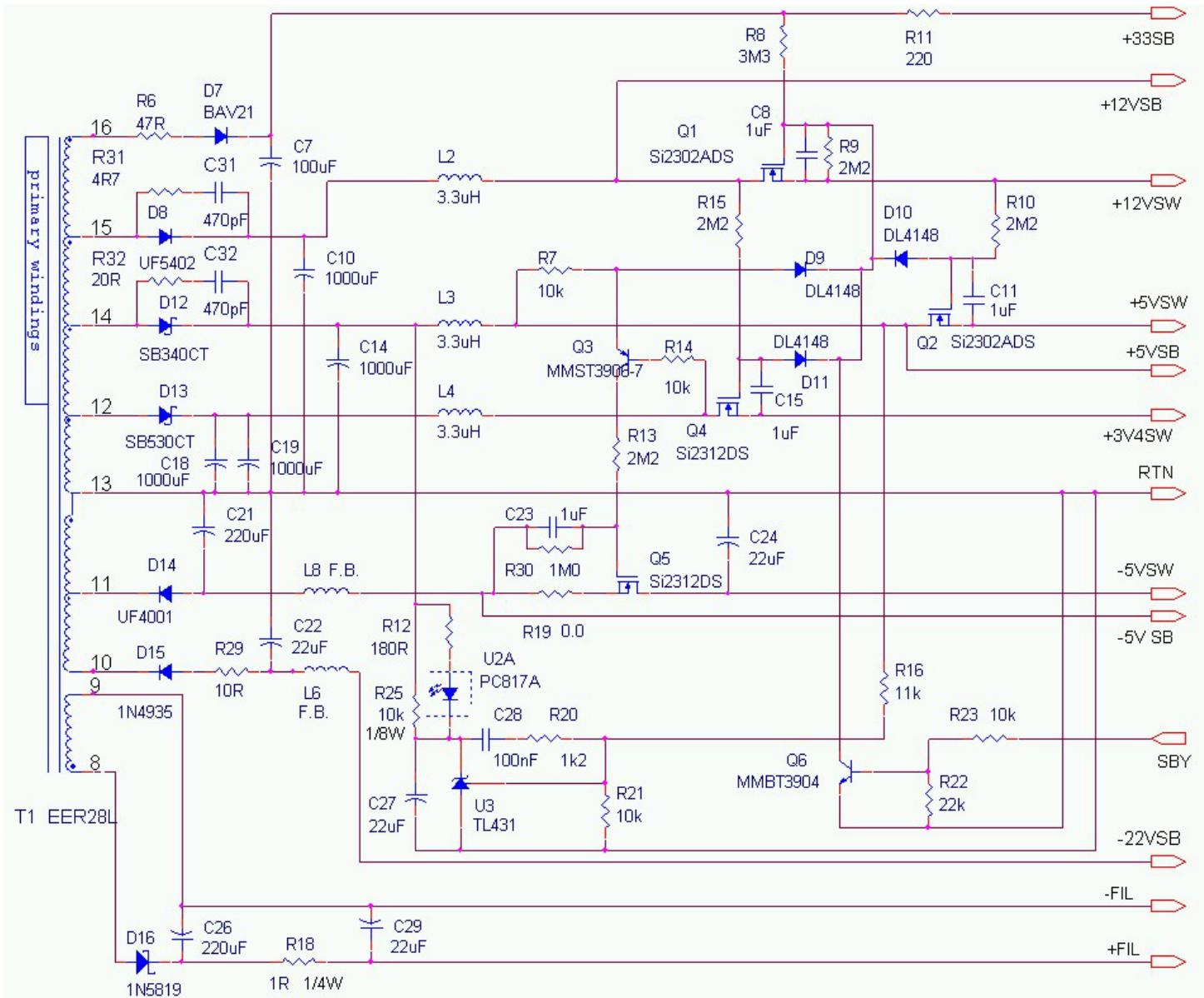


Figure 3 – Schematic (Secondary Side)

Note: 1- R30 was fitted in parallel with C23, it was not included in the original layout.
 2- Snubber networks R31, R32, C31, & C32 were fitted in parallel with D8 and D12, and were not included in the original layout



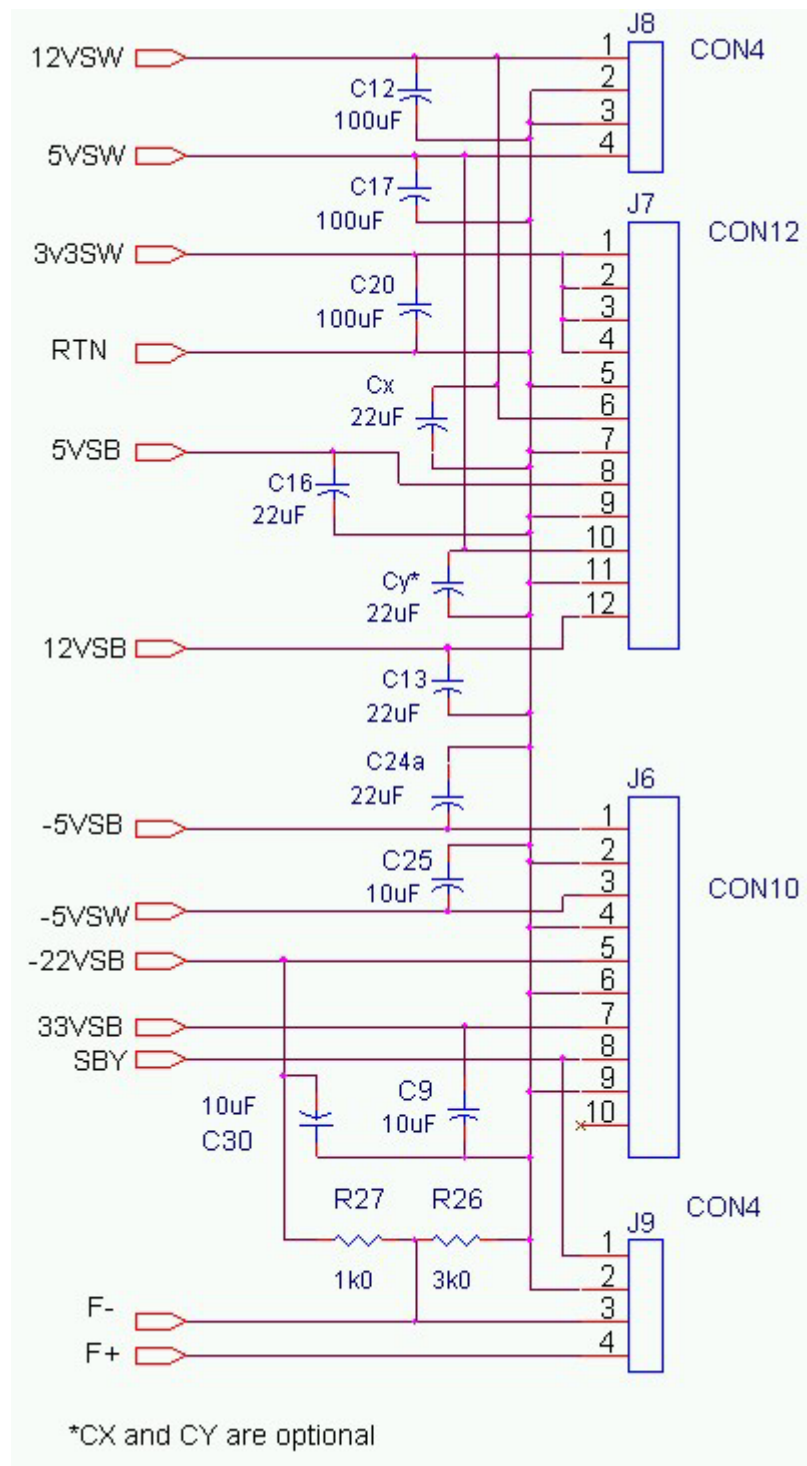


Figure 4 – Schematic (Connector Side)



4 Bill Of Materials

| Item Number | Qty. | Part Reference | Value | Description |
|-------------|------|---------------------------------|-----------|---|
| 1 | 1 | C1 | 22uF/400V | |
| 2 | 1 | C2 | 22uF/400V | |
| 3 | 1 | C3 | 1nF/1KV | |
| 4 | 1 | C4 | 100nF | Cap,Cer, 0.10 uF, 50V, Z5U, 20% |
| 5 | 1 | C5 | 47uF | Cap,Al Elect,47uF,16V,5mmX11.5mm,LXZ Series,NIPPON CHEMI-CON |
| 6 | 1 | C6 | 47uF | Cap,Al Elect,47uF,16V,5mmX11.5mm,LXZ Series,NIPPON CHEMI-CON |
| 7 | 1 | C7 | 100uF | Cap,Al Elect,100uF,50V,8mmX12mm,LXZ Series,NIPPON CHEMI-CON |
| 8 | 4 | C8 C11 C15 C23 | 1uF | CAP 1uF 25V CERM CHIP X7R 0805 SMD |
| 9 | 3 | C9 C25 C30 | 10uF | Cap,Al Elect,12uF,50V,5mmX11.5mm,LXZ Series,NIPPON CHEMI-CON |
| 10 | 4 | C10 C14 C18 C19 | 1000uF | Cap,Al Elect,1000uF,16V,10mmX20mm,LXZ Series,NIPPON CHEMI-CON |
| 11 | 3 | C12 C17 C20 | 100uF | Cap,Al Elect,100uF,50V,8mmX11.5mm,KZE Series,NIPPON CHEMI-CON |
| 12 | 8 | C13 C16 C22 C24 C24a C27 CX CY* | 22uF | Cap,Al Elect,22uF,50V,5mmX11mm,KZE Series,NIPPON CHEMI-CON |
| 13 | 1 | C21 | 220uF | Cap,Al Elect,220uF,16V,6.3mmX11mm,LXZ Series,NIPPON CHEMI-CON |
| 14 | 1 | C26 | 220uF | Cap,Al Elect,220uF,10V,6.3mmX11mm,KZE Series,NIPPON CHEMI-CON |
| 15 | 1 | C28 | 100nF | CAP 0.1uF 50V CERM CHIP X7R 0805 SMD |
| 16 | 1 | C29 | 22uF | Cap,Al Elect,22uF,50V,5mmX11.5mm,LXZ Series,NIPPON CHEMI-CON |
| 16a | 2 | C31, C32 | 470pf | Cap,Cer, 470pF, 1kV, Z5U, 20% |
| 17 | 4 | D1 D2 D3 D4 | 1N4005 | Rectifier GPP 600V 1A DO-41 |
| 18 | 1 | D5 | 1N4007GP | Rectifier GPP 1000V 1A DO-41 |
| 19 | 1 | D6 | BAV20 | |
| 20 | 1 | D7 | BAV21 | Diode Fast Switch 250V 500MW DO35 |
| 21 | 1 | D8 | UF5402 | Rectifier Ultrafast 200V, 1A, D0-201AD |
| 22 | 3 | D9 D10 D11 | DL4148 | RECT,DL4148, PASSIVATED 500mW SMD MELF |
| 23 | 1 | D12 | SB340CT | Rectifier Schottky 3A 40V DO-201AD |
| 23a | 1 | D13 | SB530CT | Rectifier Schottky 5A 30V DO-201AD |
| 24 | 1 | D14 | UF4001 | Rectifier Ultrafast 50V, 1A, D0-41 |
| 25 | 1 | D15 | 1N4935 | Rectifier Fast Rec 200V 1A DO-41 |
| 26 | 1 | D16 | 1N5819 | Rectifier Schottky 1A 40V DO-41 |
| 27 | 1 | F1 | 2A | FUSE T-LAG 2A,250V Slo-Blo IEC SHORT TR5 |
| 28 | 2 | J1 J2 | TERM_1Pin | Terminal,1Pin,18AWG |
| 29 | 1 | J6 | CON10 | |



| | | | | |
|-----|---|------------|-------------|---|
| 30 | 1 | J7 | CON12 | |
| 31 | 1 | J8 | CON4 | |
| 32 | 1 | J9 | CON4 | |
| 33 | 1 | L1 | 10mH / 0.8A | |
| 34 | 3 | L2 L3 L4 | 3.3uH | Inductor,3.3uH,2.66A |
| 35 | 2 | L6 L8 | F.B. | Bead,Ferrite,2.0 uH,Axial |
| 36 | 1 | L9 | 680uH | COIL 680.uH MOLDED SHIELDED |
| 37 | 1 | Q1 | Si2302ADS | |
| 38 | 1 | Q2 | Si2302ADS | |
| 39 | 1 | Q3 | MMST3906-7 | TRANSISTOR,2N3906, PNP 40V SOT-323 |
| 40 | 1 | Q4 | Si2312DS | |
| 41 | 1 | Q5 | Si2312DS | |
| 42 | 1 | Q6 | MMBT3904 | |
| 43 | 1 | R1 | 200k | Res, 200K, 1/4W, 5%, Carbon Film |
| 44 | 1 | R2 | 100R | Res, 100, 1/4W, 5%, Carbon Film |
| 45 | 1 | R3 | 2M2 | Res, 2.2M, 1/2W, 5%, Carbon Film |
| 46 | 1 | R4 | 6R8 | Res, 6.8, 1/4W, 5%, Carbon Film |
| 47 | 1 | R5 | 220R | Res, 220, 1/4W, 5%, Carbon Film |
| 48 | 1 | R6 | 47R | Res, 47, 1/4W, 5%, Carbon Film |
| 49 | 2 | R7 R21 | 10k | Res,10K 1/10W 1% 0805 SMD |
| 50 | 1 | R8 | 3M3 | Res, 3.3M, 1/4W, 5%, Carbon Film |
| 51 | 3 | R9 R10 R15 | 2M2 | Res,2.2M 1/8W 5% 1206 SMD |
| 52 | 1 | R11 | 220 | Res, 220R, 1/4W, 5%, Carbon Film |
| 53 | 1 | R12 | 180R | Res, 180, 1/4W, 5%, Carbon Film |
| 54 | 1 | R13 | 2M2 | Res, 2.2M, 1/4W, 5%, Carbon Film |
| 55 | 2 | R14 R23 | 10k | Res, 10K, 1/4W, 5%, Carbon Film |
| 56 | 1 | R16 | 11k | Res, 11K, 1/4W, 5%, Carbon Film |
| 57 | 1 | R18 | 1R | Res, 1, 1/4W, 5%, Metal Film |
| 58 | 1 | R19 | 0 | Res,XXX 1/10W 1% 0805 SMD |
| 59 | 1 | R20 | 1k2 | Res,1.2K 1/10W 5% 0805 SMD |
| 60 | 1 | R22 | 22k | Res, 22K, 1/4W, 5%, Carbon Film |
| 61 | 1 | R24 | 4k7 | Res, 4.7K, 1/4W, 5%, Carbon Film |
| 62 | 1 | R25 | 10k | Res, 10K, 1/8W, 5%, Carbon Film |
| 63 | 1 | R26 | 3k0 | Res, 3.0K, 1/4W, 5%, Carbon Film |
| 63a | | R27 | 1K0 | Res, 1.0K, 1/4W, 5%, Carbon Film |
| 64 | 1 | R28 | 750R | Res, 750, 1/2W, 5%, Carbon Film |
| 65 | 1 | R29 | 10R | Res, 10, 1/4W, 5%, Carbon Film |
| 66 | 1 | R30 | 1M0 | Res,1.0M 1/10W 5% 0805 SMD |
| 66a | 1 | R31 | 4R7 | Res, 4R7, 1/8W, 5%, Carbon Film |
| 66b | 1 | R32 | 20R | Res, 20R, 1/8W, 5%, Carbon Film |
| 67 | 1 | T1 | EER28L | Custom (See Spec) |
| 68 | 1 | U1 | TOP245P | TOPSwitch |
| 69 | 1 | U2 | PC817X1 | IC,PC817A1,PHOTOCOUPLER TRAN OUT CTR 80-160% 4-DIP |
| 70 | 1 | U3 | TL431 | Shunt regulator 1% |



5 Layout

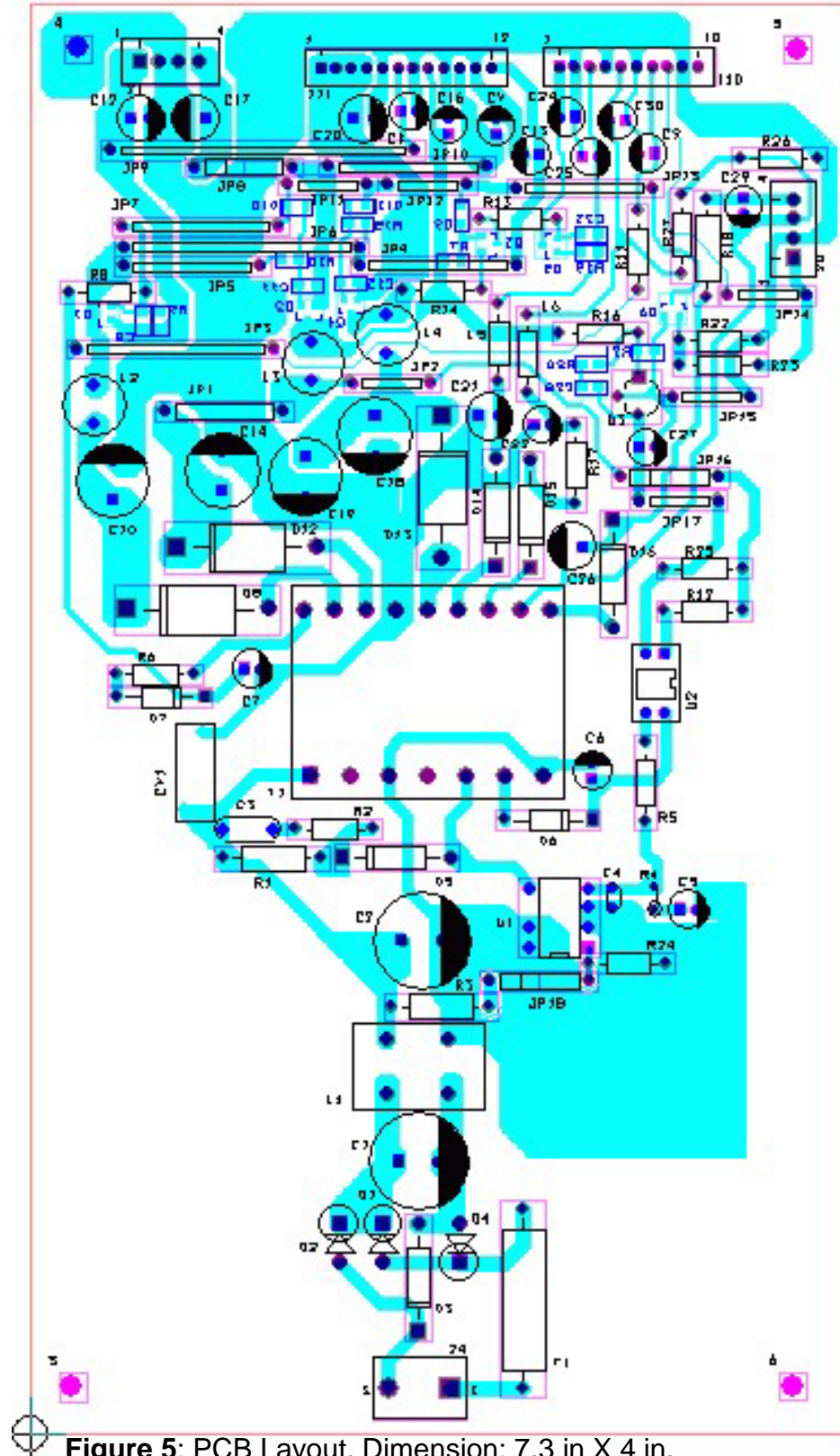


Figure 5: PCB Layout. Dimension: 7.3 in X 4 in.

Note: Some components were added and are not shown above (see schematic note).



6 Transformer Specification

6.1 Electrical Diagram

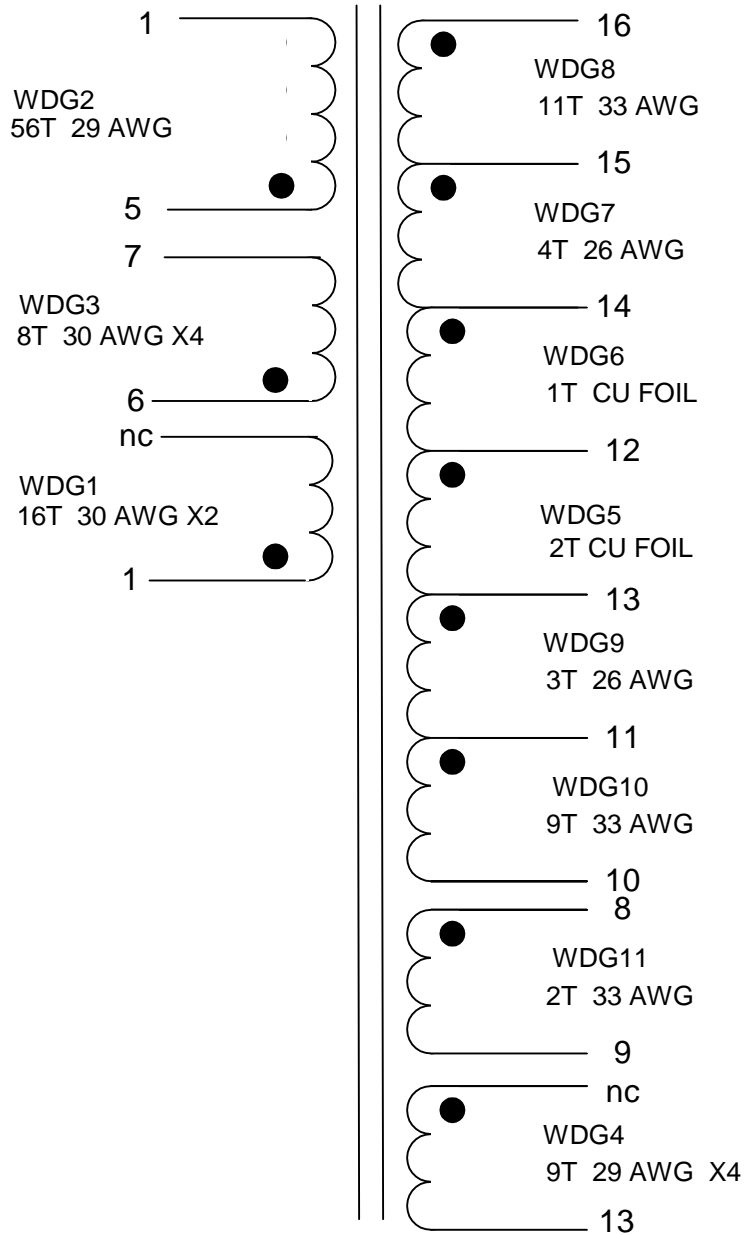


Figure 6 –Transformer Electrical Diagram



6.2 Electrical Specifications

| | | |
|-----------------------------------|--|-------------------|
| Electrical Strength | 1 second, 60 Hz, from Pins 1-7 to Pins 8-16 | 3000 VAC |
| Primary Inductance | Pins 1-5, all other windings open, measured at 100 kHz, 0.4 VRMS | 550 μ H, +10% |
| Resonant Frequency | Pins 1-5, all other windings open | 750 kHz (Min.) |
| Primary Leakage Inductance | Pins 1-5, with Pins 8-16 shorted, measured at 100 kHz, 0.4 VRMS | 40 μ H (Max.) |

6.3 Materials

| Item | Description |
|------|---|
| [1] | Core: EER28L |
| [2] | Bobbin: BEER28L, VERTICAL 16-PINS |
| [3] | Magnet Wire: 30 AWG |
| [4] | Magnet Wire: 29 AWG |
| [5] | Magnet Wire: 33 AWG |
| [6] | Magnet Wire: 26 AWG |
| [7] | Tape: Margin 6 mm |
| [8] | Tape, Tape: 3M 1298 Polyester Film, 10.5mm wide |
| [9] | Tape, Tape: 3M 1298 Polyester Film, 22mm wide |
| [10] | Tape, Tape: 3M 1298 Polyester Film, 14mm wide |
| [11] | Copper Foil: 1mil x 9.5mm wide x 190 mm long |
| [12] | Varnish |



6.4 Transformer Build Diagram

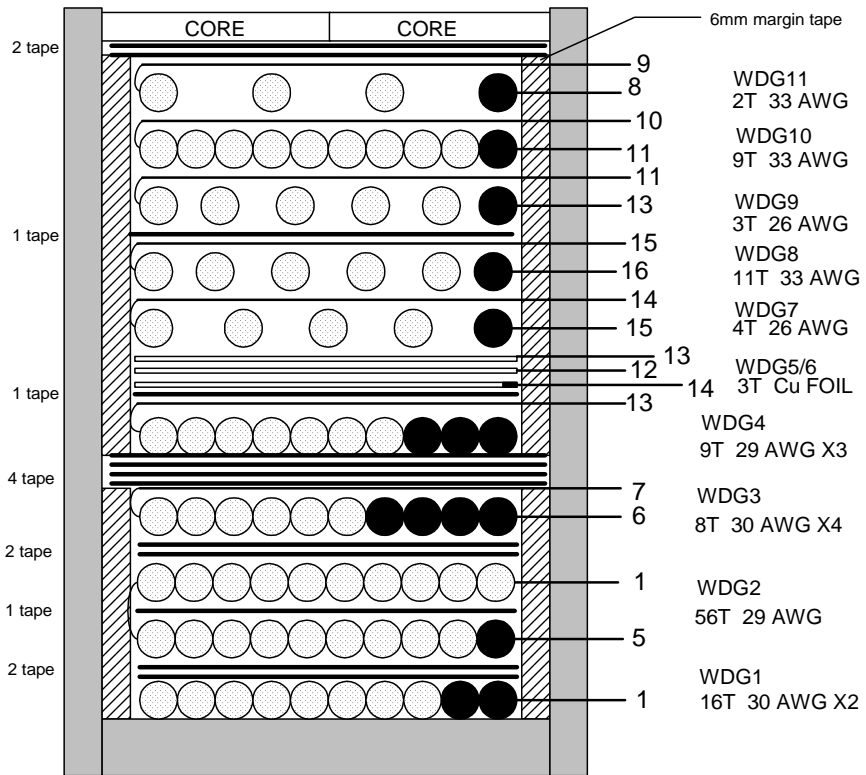


Figure 7 – Transformer Build Diagram.

6.4.1 WDG5/6 Copper Foil build diagram:

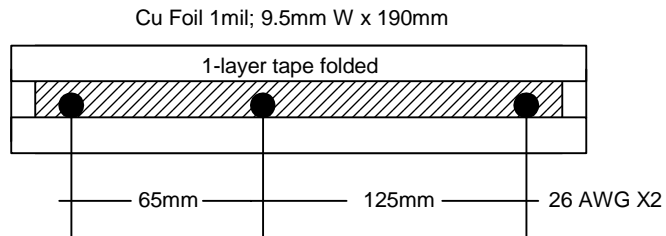


Figure 8 – Copper Foil Build Diagram.



6.5 Transformer Construction

| | |
|---|--|
| Bobbin Preparation | Pull Pins 2, 3 & 4 on bobbin to provide polarization. Place the bobbin with pins oriented on the right hand side. |
| Margin | Apply 6 mm wide margin tape on both sides of the bobbin. Match height of primary windings. |
| WGD1: Shield | Start at Pin 1. Wind 16 bifilar turns of 30 AWG wire in 1 layer. Cut end leads floating. |
| Basic Insulation | Use two layers of 10.5 mm tape for basic insulation. |
| WGD2: Primary (1st-layer) | Start at Pin 5. Wind 30 turns of 29 AWG wire for the 1 st layer. |
| Basic Insulation | Put one layer of 10.5 mm tape for basic insulation |
| WGD2: Primary (2nd-layer) | Continue winding 26 turns for the 2 nd layer. Finish on Pin 1. |
| Basic Insulation | Put two layers of 10.5 mm tape for basic insulation |
| WGD3: Bias | Start at Pin 6. Wind 8 quadfilar turns of 30 AWG wire in 1 layer. Finish on Pin 7. |
| Reinforced Insulation | Put 4 layers of 22 mm tape for reinforced insulation |
| Margin | Apply 6 mm wide margin tape on both sides of the bobbin. Match height of secondary windings. |
| WGD4: Bias | Start at Pin 16 temporarily. Wind 9 quadfilar turns of 29 AWG wire in 1 layer. Finish on Pin 13. Cut start-leads floating. |
| Basic Insulation | Put one layer of 10.5mm tape for basic insulation |
| WGD5/6: 3V/5V | Use prepared cu foil shown in Figure 7. Start at pin 14, wind 1 turn, terminate at pin 12, continue to wind two turns. Finish at pin 13. Secure end with 10.5 mm tape. |
| WGD7: 12V | Start at Pin 15. Wind 4 turns of 26 AWG wire in 1 layer. Spread evenly across the bobbin. Finish on Pin 14. |
| WGD8: 33V | Start at Pin 16. Wind 11 turns of 33 AWG wire in 1 layer. Spread evenly across the bobbin. Finish on Pin 15. |
| Basic Insulation | Put one layer of 10.5 mm tape for basic insulation |
| WGD9: - 5V | Start at Pin 13. Wind 3 turns of 26 AWG wire in 1 layer. Spread evenly across the bobbin. Finish on Pin 11. |
| WGD10: - 22V | Start at Pin 11. Wind 9 turns of 33 AWG wire in 1 layer. Spread evenly across the bobbin. Finish on Pin 10. |
| WGD11: 3V VFD | Start at Pin 8. Wind 2 turns of 33 AWG wire in 1 layer. Spread evenly across the bobbin. Finish on Pin 9. |
| Outer Wrap | Wrap windings with 2 layers of 22 mm tape |
| Core Preparation | Glue core halves together. |
| Final Assembly | Varnish impregnate |



7 Transformer Spreadsheets

| ACDC_TOPGX_Rev1.5_081203 Copyright Power Integrations Inc. 2003 | | INPUT | INFO | OUTP UT | UNIT | TOP_GX_081203.xls: TOPSwitch-GX Continuous/Discontinuous Flyback Transformer Design Spreadsheet |
|--|--|-------------|-------------|--------------|---------------|---|
| ENTER APPLICATION VARIABLES | | | | | | Customer |
| VACMIN | | 90 | | | Volts | Minimum AC Input Voltage |
| VACMAX | | 280 | | | Volts | Maximum AC Input Voltage |
| fL | | 50 | | | Hertz | AC Mains Frequency |
| VO | | 5 | | | Volts | Output Voltage |
| PO | | 25 | | | Watts | |
| n | | 0.75 | | | | Efficiency Estimate |
| Z | | 0.75 | | | | Loss Allocation Factor |
| VB | | 15 | | | Volts | Bias Voltage |
| tC | | 3 | | | mSeco nds | Bridge Rectifier Conduction Time Estimate |
| CIN | | 44 | | | uFarad s | Input Filter Capacitor |
| ENTER TOPSWITCH-GX VARIABLES | | | | | | |
| TOP-GX | | TOP2 45P | | | Univer sal | 115 Doubled/230V |
| Chosen Device | | | TOP24 5P | Power Out | 22W | 30W |
| KI | | 1 | | | | External Ilimit reduction factor (KI=1.0 for default ILIMIT, KI <1.0 for lower ILIMIT) |
| ILIMITMIN | | | | | 1.023 Amps | Use 1% resistor in setting external ILIMIT |
| ILIMITMAX | | | | | 1.177 Amps | Use 1% resistor in setting external ILIMIT |
| Frequency - (F)=132kHz, (H)=66kHz | | F | | | | Full (F) frequency option - 132kHz |
| fS | | 13200 | | | 13200 Hertz | TOPSwitch-GX Switching Frequency: Choose between 132 kHz and 66 kHz |
| fSmin | | 0 | | | 0 | |
| fSmax | | | | | 12400 Hertz | TOPSwitch-GX Minimum Switching Frequency |
| VOR | | 103 | | | 0 | |
| VDS | | 10 | | | 14000 Hertz | TOPSwitch-GX Maximum Switching Frequency |
| VD | | 0.5 | | | 0 | |
| VDB | | 0.7 | | | Volts | Reflected Output Voltage |
| KP | | 0.50 | | | Volts | TOPSwitch on-state Drain to Source Voltage |
| | | | | | Volts | Output Winding Diode Forward Voltage Drop |
| | | | | | Volts | Bias Winding Diode Forward Voltage Drop |
| | | | | | | Ripple to Peak Current Ratio (0.4 < KRP < 1.0 : 1.0< KDP<6.0) |



**ENTER TRANSFORMER
CORE/CONSTRUCTION
VARIABLES**

| | | | | |
|-----------|-------|------------------------|---|--|
| Core Type | EER2 | | | |
| | 8L | | | |
| Core | EER28 | P/N: | PC40EER28L-Z | |
| | L | | | |
| Bobbin | EER28 | P/N: | BEER-28L-1112CPH | |
| | L_BOB | | | |
| | BIN | | | |
| AE | | 0.814 cm ² | Core Effective Cross Sectional Area | |
| LE | | 7.55 cm | Core Effective Path Length | |
| AL | | 2520 nH/T ² | Ungapped Core Effective Inductance | |
| BW | 21.5 | 21.5 mm | Bobbin Physical Winding Width | |
| M | 6 | mm | Safety Margin Width (Half the Primary to Secondary Creepage Distance) | |
| L | 2.1 | | Number of Primary Layers | |
| NS | 3 | | Number of Secondary Turns | |

**DC INPUT VOLTAGE
PARAMETERS**

| | | |
|------|-----------|--------------------------|
| VMIN | 75 Volts | Minimum DC Input Voltage |
| VMAX | 396 Volts | Maximum DC Input Voltage |

**CURRENT WAVEFORM SHAPE
PARAMETERS**

| | | |
|-------|-----------|-------------------------|
| DMAX | 0.61 | Maximum Duty Cycle |
| I AVG | 0.45 Amps | Average Primary Current |
| IP | 0.97 Amps | Peak Primary Current |
| IR | 0.48 Amps | Primary Ripple Current |
| IRMS | 0.58 Amps | Primary RMS Current |

**TRANSFORMER PRIMARY
DESIGN PARAMETERS**

| | | |
|-----|-----------------------|---|
| LP | 717 uHenries | Primary Inductance |
| NP | 56 | Primary Winding Number of Turns |
| NB | 9 | Bias Winding Number of Turns |
| ALG | 227 nH/T ² | Gapped Core Effective Inductance |
| BM | 1518 Gauss | Maximum Flux Density at PO, VMIN (BM<3000) |
| BP | 1846 Gauss | Peak Flux Density (BP<4200) |
| BAC | 380 Gauss | AC Flux Density for Core Loss Curves (0.5 X Peak to Peak) |
| ur | 1860 | Relative Permeability of Ungapped Core |
| LG | 0.41 mm | Gap Length (Lg > 0.1 mm) |
| BWE | 19.95 mm | Effective Bobbin Width |
| OD | 0.36 mm | Maximum Primary Wire Diameter including insulation |
| INS | 0.06 mm | Estimated Total Insulation Thickness (= 2 * film thickness) |
| DIA | 0.30 mm | Bare conductor diameter |



| | | | |
|--|-------|-------------------|--|
| AWG | | 29 AWG | Primary Wire Gauge (Rounded to next smaller standard AWG value) |
| CM | | 128 Cmils | Bare conductor effective area in circular mils |
| CMA | | 221 Cmils/ Amp | Primary Winding Current Capacity (200 < CMA < 500) |
| | | | |
| TRANSFORMER SECONDARY DESIGN PARAMETERS (SINGLE OUTPUT / SINGLE OUTPUT EQUIVALENT) Lumped parameters | | | |
| ISP | | 18.13 Amps | Peak Secondary Current |
| ISRMS | | 8.60 Amps | Secondary RMS Current |
| IO | | 5.00 Amps | Power Supply Output Current |
| IRIPPLE | | 7.00 Amps | Output Capacitor RMS Ripple Current |
| | | | |
| CMS | | 1721 Cmils | Secondary Bare Conductor minimum circular mils |
| AWGS | | 17 AWG | Secondary Wire Gauge (Rounded up to next larger standard AWG value) |
| DIAS | | 1.15 mm | Secondary Minimum Bare Conductor Diameter |
| ODS | | 3.17 mm | Secondary Maximum Outside Diameter for Triple Insulated Wire |
| INSS | | 1.01 mm | Maximum Secondary Insulation Wall Thickness |
| | | | |
| VOLTAGE STRESS PARAMETERS | | | |
| VDRAIN | | 632 Volts | Maximum Drain Voltage Estimate (Includes Effect of Leakage Inductance) |
| PIVS | | 26 Volts | Output Rectifier Maximum Peak Inverse Voltage |
| PIVB | | 75 Volts | Bias Rectifier Maximum Peak Inverse Voltage |
| | | | |
| TRANSFORMER SECONDARY DESIGN PARAMETERS (MULTIPLE OUTPUTS) 1st output | | | |
| VO1 | 3.4 | Volts | Output Voltage |
| IO1 | 2.550 | Amps | Output DC Current |
| PO1 | | 8.67 Watts | Output Power |
| VD1 | 0.5 | Volts | Output Diode Forward Voltage Drop |
| NS1 | | 2.13 | Output Winding Number of Turns |
| ISRMS1 | | 4.388 Amps | Output Winding RMS Current |
| IRIPPLE1 | | 3.57 Amps | Output Capacitor RMS Ripple Current |
| PIVS1 | | 18 Volts | Output Rectifier Maximum Peak Inverse |



| | | | Voltage |
|-------------|-------|-------------|--|
| CMS1 | | 878 Cmils | Output Winding Bare Conductor minimum circular mils |
| AWGS1 | | 20 AWG | Wire Gauge (Rounded up to next larger standard AWG value) |
| DIAS1 | | 0.81 mm | Minimum Bare Conductor Diameter |
| ODS1 | | 4.47 mm | Maximum Outside Diameter for Triple Insulated Wire |
| 2nd output | | | |
| VO2 | 12.2 | Volts | Output Voltage |
| IO2 | 0.850 | Amps | Output DC Current |
| PO2 | | 10.37 Watts | Output Power |
| VD2 | 1.2 | Volts | Output Diode Forward Voltage Drop |
| NS2 | | 7.31 | Output Winding Number of Turns |
| ISRMS2 | | 1.463 Amps | Output Winding RMS Current |
| IRIPPLE2 | | 1.19 Amps | Output Capacitor RMS Ripple Current |
| PIVS2 | | 64 Volts | Output Rectifier Maximum Peak Inverse Voltage |
| CMS2 | | | |
| | | 293 Cmils | Output Winding Bare Conductor minimum circular mils |
| AWGS2 | | 25 AWG | Wire Gauge (Rounded up to next larger standard AWG value) |
| DIAS2 | | 0.46 mm | Minimum Bare Conductor Diameter |
| ODS2 | | 1.30 mm | Maximum Outside Diameter for Triple Insulated Wire |
| 3rd output | | | |
| VO3 | 33.0 | Volts | Output Voltage |
| IO3 | 0.002 | Amps | Output DC Current |
| PO3 | | 0.07 Watts | Output Power |
| VD3 | 1.0 | Volts | Output Diode Forward Voltage Drop |
| NS3 | | 18.55 | Output Winding Number of Turns |
| ISRMS3 | | 0.003 Amps | Output Winding RMS Current |
| IRIPPLE3 | | 0.00 Amps | Output Capacitor RMS Ripple Current |
| PIVS3 | | 164 Volts | Output Rectifier Maximum Peak Inverse Voltage |
| CMS3 | | | |
| | | 1 Cmils | Output Winding Bare Conductor minimum circular mils |
| AWGS3 | | 51 AWG | Wire Gauge (Rounded up to next larger standard AWG value) |
| DIAS3 | | 0.02 mm | Minimum Bare Conductor Diameter |
| ODS3 | | 0.51 mm | Maximum Outside Diameter for Triple Insulated Wire |
| Total power | | 19.10 Watts | !!!!!!!!! Warning: total output power not equal to PO (PO= 25 W) |
| | | 6 | |



8 Performance Data

All measurements performed at room temperature, 60 Hz input frequency, unless otherwise specified.

8.1 Efficiency

Load Condition: 3.3Vsb/2A; 5Vsw/0.4A; 5Vsb/0.4A; 12Vsw/0.3A, 12Vsb/0.1A; -5Vsw/0.1A; -5Vsb/240 ohms, -22Vsb/11K; +33Vsb/16Kohms; 3.3V VFD/20 ohms

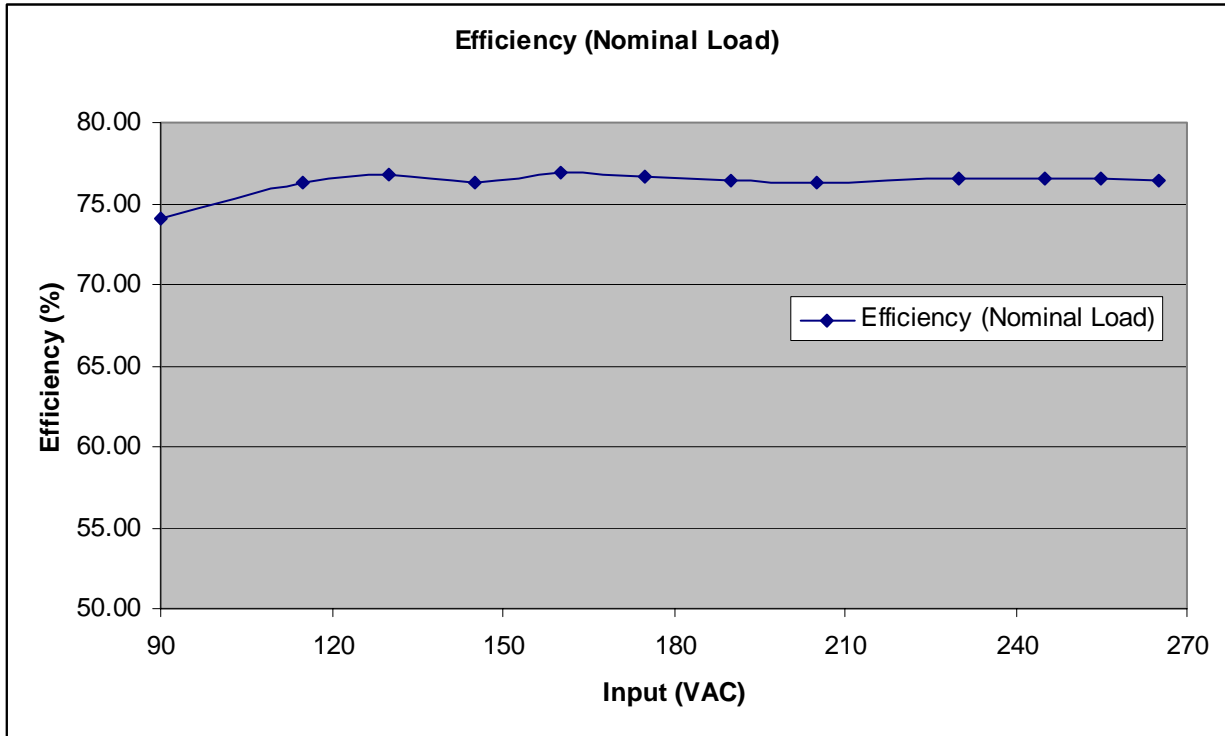


Figure 9- Efficiency vs. Input Voltage, Room Temperature, 60 Hz. Efficiency at 115Vac and 230Vac are 76.3% and 76.5% respectively.



8.2 Cross Regulation

8.2.1 Nominal load

Load Condition: 3.3Vsb/2A; 5Vsw/0.4A; 5Vsb/0.4A; 12Vsw/0.3A, 12Vsb/0.1A; -5Vsw/0.08A; -5Vsb/240 ohms, -22Vsb/11K; +33Vsb/16Kohms; 3.3V VFD/20 ohms

| Vout (VDC) | Load (A) | @115V | @230V |
|------------|----------|--------|--------|
| 3.3Vsb | 2A | 3.25 V | 3.25 |
| 5Vsw/ | 0.4A | 5.27 | 5.27 |
| 5Vsb/ | 0.4A | 5.28 | 5.28 |
| 12Vsw | 0.3A | 12.50 | 12.46 |
| 12Vsb | 0.1A | 12.51 | 12.47 |
| -5Vsw | 0.08A | -5.08 | -5.15 |
| -5Vsb | 240 ohms | -5.17 | -5.15 |
| -22Vsb | 11K | -22.81 | -22.71 |
| +33Vsb | 16Kohms | 33.07 | 32.94 |
| 3.3V VFD | 20 ohms | 3.24 | 3.24 |

Figure 9 –Nominal load at Room Temperature.

8.2.2 Peak Load (One output at a time)

At 115V

| Vout | Iout | Vout (measured) | Iout | Vout (measured) | Iout | Vout (measured) | Iout | Vout (measured) |
|-------------|---------------------------|-----------------|--------------------------|-----------------|---------------------------|-----------------|--------------------------|-----------------|
| 3.3Vs b | 2.51A_{pk} | 3.15 V | 2A | 3.27 V | 2A | 3.23 V | 2A | 3.21 V |
| 5Vsw/ | 0.4A | 5.27 | 1.2A_{pk} | 5.22 | 0.4A | 5.27 | 0.4A | 5.27 |
| 5Vsb/ | 0.4A | 5.28 | 0.4A | 5.28 | 0.55A_{pk} | 5.28 | 0.4A | 5.28 |
| 12Vsw | 0.3A | 12.5 | 0.3A | 12.71 | 0.3A | 12.52 | 1.2A_{pk} | 12.2 |
| 12Vsb | 0.1A | 12.51 | 0.1A | 12.72 | 0.1A | 12.53 | 0.1A | 12.26 |
| -5Vsw | 0.08A | -5.22 | 0.08A | -5.37 | 0.08A | -5.21 | 0.08A | -5.41 |
| -5Vsb | 240 Ω | -5.22 | 240 Ω | -5.37 | 240 Ω | -5.21 | 240 Ω | -5.41 |
| - 22Vsb | 11K Ω | -22.92 | 11K Ω | -23.5 | 11K Ω | -22.89 | 11K Ω | -23.58 |
| +33Vs b | 16K Ω | 33.26 | 16K Ω | 34.05 | 16K Ω | 33.23 | 16K Ω | 34.05 |
| 3.3V VFD | 20 Ω | 3.25 | 20 Ω | 3.31 | 20 Ω | 3.26 | 20 Ω | 3.26 |



Continuation (115V)

| Vout | Iout | Vout (measured) | Iout | Vout (measured) |
|-------------|---------------|--------------------|----------------|--------------------|
| 3.3Vs b | 2A | 3.22 V | 2A | 3.22 V |
| 5Vsw/ | 0.4A | 5.27 | 0.4A | 5.29 |
| 5Vsb/ | 0.4A | 5.28 | 0.4A | 5.28 |
| 12Vsw | 0.3A | 12.38 | 0.3A | 12.46 |
| 12Vsb | 0.4Apk | 12.51 V | 0.1A | 12.47 |
| -5Vsw | 0.08A | -5.23 | 0.12Apk | -5.0 V |
| -5Vsb | 240 Ω | -5.24 | 240 Ω | -5.0 |
| - 22Vsb | 11K Ω | -22.96 | 11K Ω | -22.61 |
| +33Vs b | 16K Ω | 33.29 | 16K Ω | 33.0 |
| 3.3V VFD | 20 Ω | 3.25 | 20 Ω | 3.24 |

At 230V

| Vout | Iout | Vout (measured) | Iout | Vout (measured) | Iout | Vout (measured) | Iout | Vout (measured) |
|-------------|----------------|--------------------|---------------|--------------------|----------------|--------------------|---------------|--------------------|
| 3.3Vs b | 2.51Apk | 3.19 V | 2A | 3.29 V | 2A | 3.25 V | 2A | 3.24 V |
| 5Vsw/ | 0.4A | 5.27 | 1.2Apk | 5.22 | 0.4A | 5.27 | 0.4A | 5.27 |
| 5Vsb/ | 0.4A | 5.28 | 0.4A | 5.28 | 0.55Apk | 5.28 | 0.4A | 5.28 |
| 12Vsw | 0.3A | 12.48 | 0.3A | 12.64 | 0.3A | 12.49 | 1.2Apk | 12.22 |
| 12Vsb | 0.1A | 12.49 | 0.1A | 12.66 | 0.1A | 12.5 | 0.1A | 12.29 |
| -5Vsw | 0.08A | -5.18 | 0.08A | -5.29 | 0.08A | -5.17 | 0.08A | -5.3 |
| -5Vsb | 240 Ω | -5.18 | 240 Ω | -5.29 | 240 Ω | -5.17 | 240 Ω | -5.3 |
| - 22Vsb | 11K Ω | -22.81 | 11K Ω | -23.22 | 11K Ω | -22.77 | 11K Ω | -23.2 |
| +33Vs b | 16K Ω | 33.08 | 16K Ω | 33.67 | 16K Ω | 33.05 | 16K Ω | 33.55 |
| 3.3V VFD | 20 Ω | 3.31 | 20 Ω | 3.30 | 20 Ω | 3.26 | 20 Ω | 3.25 |



Continuation (230V)

| Vout | Iout | Vout (measured) | Iout | Vout (measured) |
|-------------|--------------------------|--------------------|---------------------------|--------------------|
| 3.3Vs b | 2A | 3.25 V | 2A | 3.25 |
| 5Vsw/ | 0.4A | 5.27 | 0.4A | 5.27 |
| 5Vsb/ | 0.4A | 5.28 | 0.4A | 5.28 |
| 12Vsw | 0.3A | 12.36 | 0.3A | 12.44 |
| 12Vsb | 0.4A_{pk} | 12.37 | 0.1A | 12.45 |
| -5Vsw | 0.08A | -5.18 | 0.12A_{pk} | -4.99 |
| -5Vsb | 240 Ω | -5.18 | 240 Ω | -4.99 |
| - 22Vsb | 11K Ω | -22.78 | 11K Ω | -22.53 |
| +33Vs b | 16K Ω | 33.04 | 16K Ω | 32.86 |
| 3.3V VFD | 20 Ω | 3.25 | 20 Ω | 3.25 |



9 Thermal Performance

Open chassis measurement. The temperature stabilized after 1 hour of continuous nominal load operation without airflow.

Load Condition: 3.3Vsb/2A; 5Vsw/0.4A; 5Vsb/0.4A; 12Vsw/0.3A, 12Vsb/0.1A; -5Vsw/0.08A; -5Vsb/240 ohms, -22Vsb/11K; +33Vsb/16Kohms; 3.3V VFD/20 ohms

| Temperature (°C) | | |
|---------------------------|-------|---------|
| Item | 90VAC | 265 VAC |
| Ambient | 25 | 25 |
| <i>TOP245P (U1)</i> | 61 | 68 |
| <i>Transformer (T1)</i> | 43 | 41 |
| <i>3V Rectifier (D13)</i> | 71 | 70 |
| <i>5V Rectifier (D12)</i> | 58 | 59 |
| <i>12V Rectifier (D8)</i> | 54 | 58 |



10 Waveforms

10.1 Drain Voltage and Current, Normal Operation

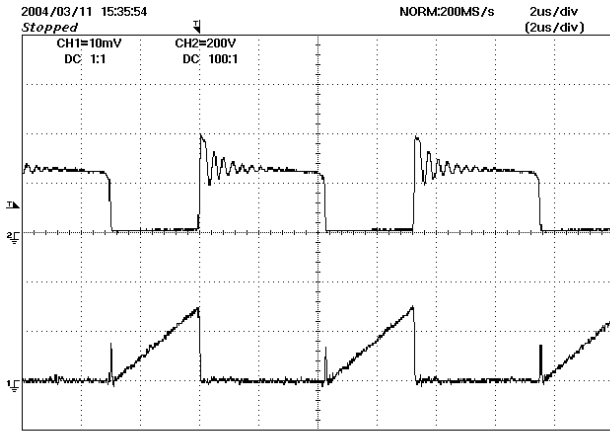


Figure 10 - 115 VAC, Nominal Load.
Upper: V_{DRAIN} , 200 V, 2 μ s / div
Lower: I_{DRAIN} , 0.5 A / div

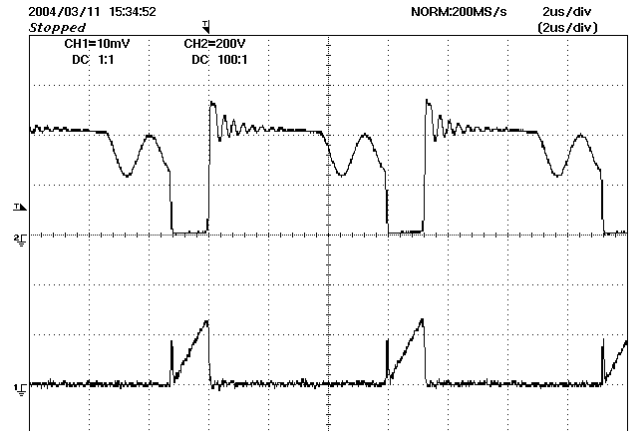


Figure 10a - 230 VAC, Nominal Load
Upper: V_{DRAIN} , 200 V / div, 2 μ s / div
Lower: I_{DRAIN} , 0.5 A / div

10.2 Drain Voltage and Current Start-up Profile

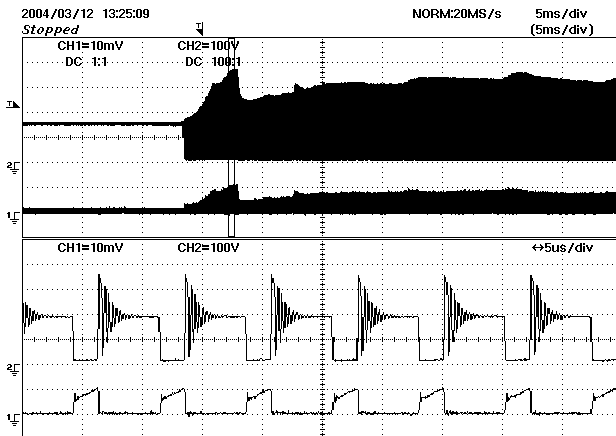


Figure 11 - 90 VAC Input and Maximum Load. Upper:
 I_{DRAIN} , V_{DRAIN} , 100 V & 5 ms / div.
Lower: 1A / div.

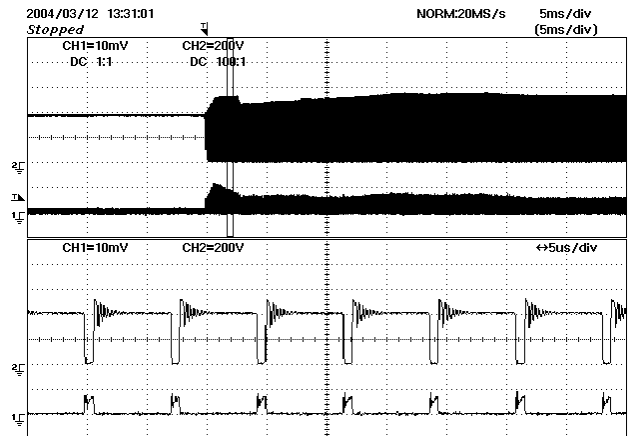


Figure 12 - 265 VAC Input and Maximum Load.
Upper: V_{DRAIN} , 200 V & 5 ms / div.
Lower: I_{DRAIN} , 1 A / div.



10.3 Output Start-up Profile

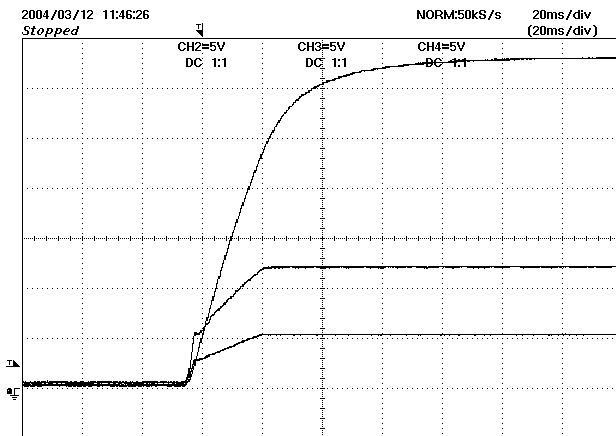


Figure 13 - 115 VAC Input and Nominal Load.
5Vsb/12Vsb/33Vsb, 5 V & 20 ms / div.

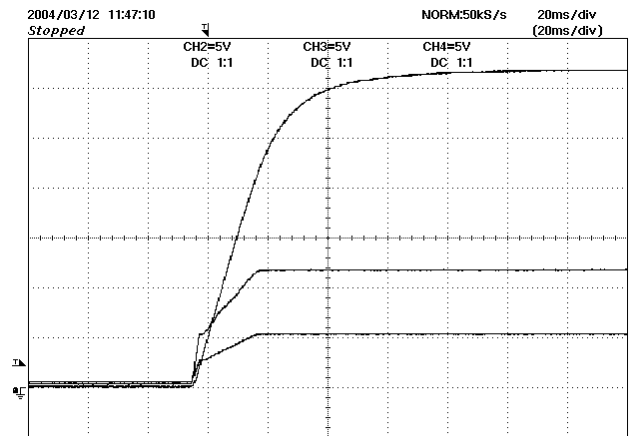


Figure 14 - 230 VAC Input and Nominal Load.
5Vsb/12Vsb/33Vsb, 5 V & 20 ms / div.



10.4 Load Transient Response (Load Step)

In the figures shown below, signal averaging was used to enable better viewing of the load transient response. The oscilloscope was triggered using the load current step as a trigger source. Since the output switching and line frequency occur essentially at random with respect to the load transient, contributions to the output ripple from these sources will average out, leaving the contribution only from the load step response.

At 5Vsb output

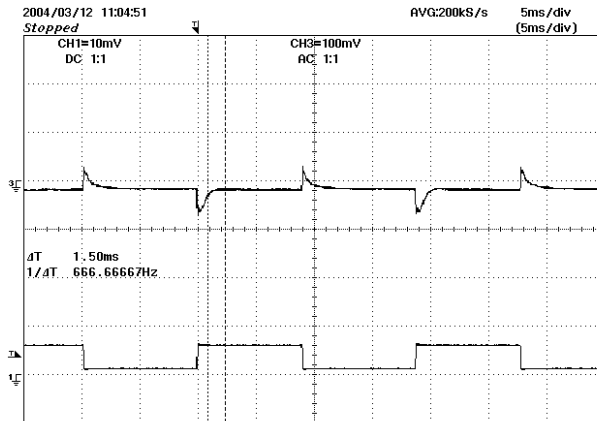


Figure 15 – Transient Response, 90 VAC, 1.2A-1.7A Load Step.
 Top: Output Voltage
 1V, 1 ms / div
 Bottom: Load Current 2 A/div



11 Output Ripple Measurements

11.1.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe must be utilized in order to reduce spurious signals due to pickup. Details of the probe modification are provided in Figure 16 and Figure 17.

The 5125BA probe adapter is affixed with two capacitors tied in parallel across the probe tip. The capacitors include one (1) 0.1 $\mu\text{F}/50\text{ V}$ ceramic type and one (1) 1.0 $\mu\text{F}/50\text{ V}$ aluminum electrolytic. ***The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be maintained (see below).***

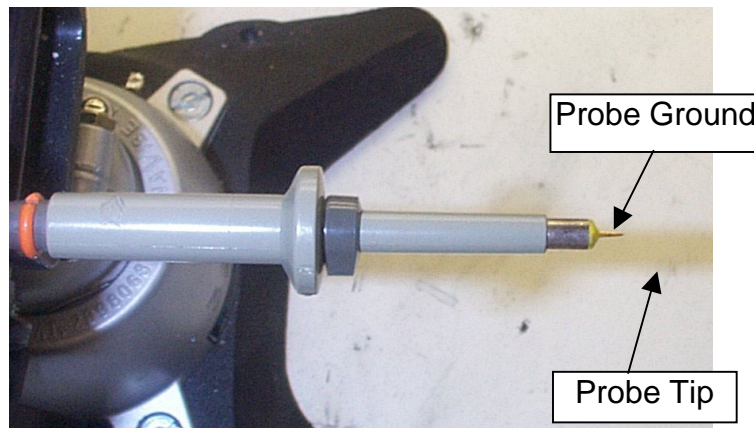


Figure 16 - Oscilloscope Probe Prepared for Ripple Measurement. (End Cap and Ground Lead Removed)

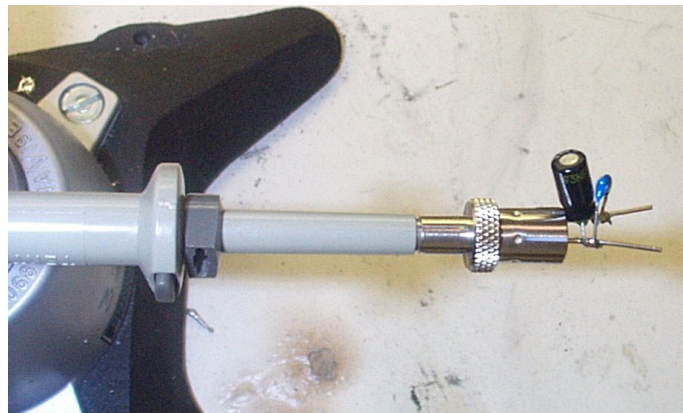


Figure 17 - Oscilloscope Probe with Probe Master 5125BA BNC Adapter. (Modified with wires for probe ground for ripple measurement, and two parallel decoupling capacitors added)

11.1.2 Measurement Results

Peak Load (One output at a time)

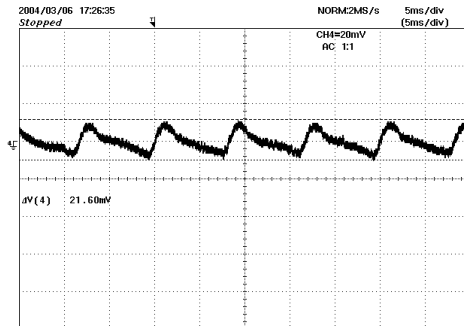


Figure 18 – 3.3Vsw Ripple, 115 VAC, Peak Load.
5 ms, 20 mV / div

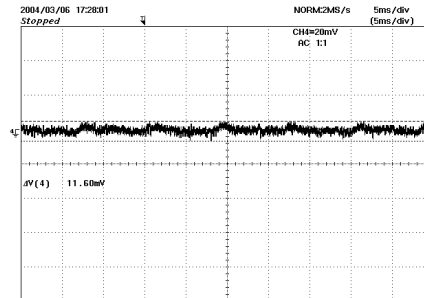


Figure 19 – 3.3 Vsw Ripple, 230 VAC, Peak Load.
5 ms, 20 mV / div

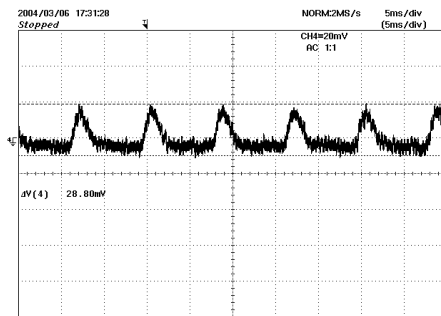


Figure 20 – 5Vsw Ripple, 115 VAC, Peak Load.
5 ms, 20 mV /div

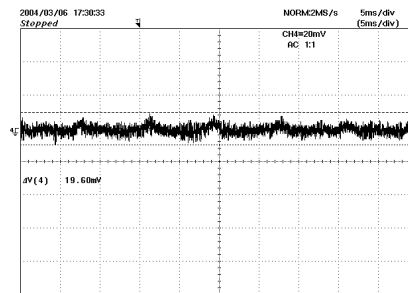


Figure 21 – 5Vsw Ripple, 230 VAC, Peak Load.
5 ms, 20 mV /div



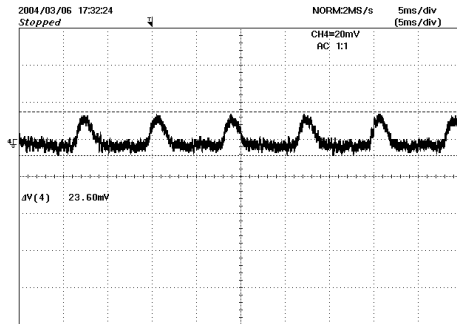


Figure 22 – 5Vsb Ripple, 115 VAC, Peak Load.
5 ms, 20 mV / div

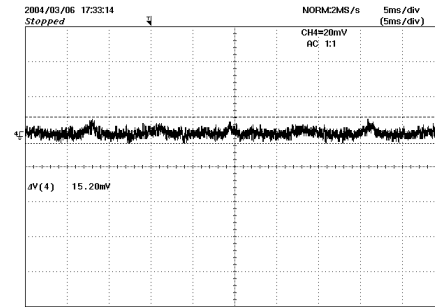


Figure 23 – 5 Vsb Ripple, 230 VAC, Full Load.
5 ms, 20 mV / div

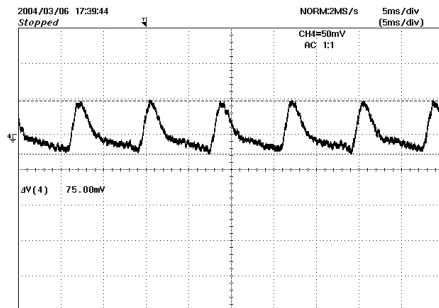


Figure 24 – 12Vsw Ripple, 115 VAC, Peak Load.
5 ms, 50 mV /div

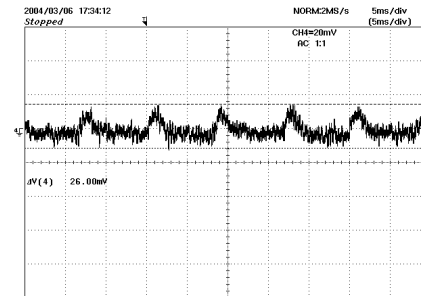


Figure 25 – 12Vsw Ripple, 230 VAC, Peak Load.
5 ms, 50 mV /div



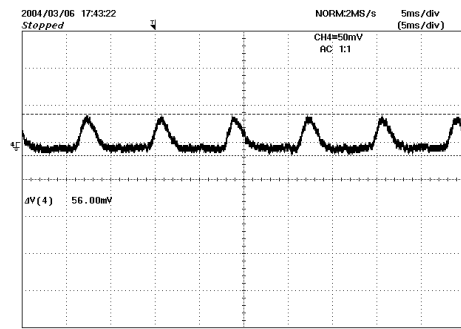


Figure 26 – 12Vsb Ripple, 115 VAC, Peak Load.
5 ms, 50 mV / div

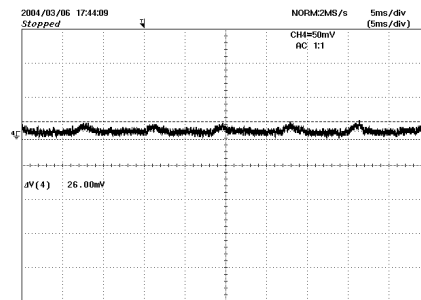


Figure 27 – 12 Vsb Ripple, 230 VAC, Peak Load.
5 ms, 50 mV / div

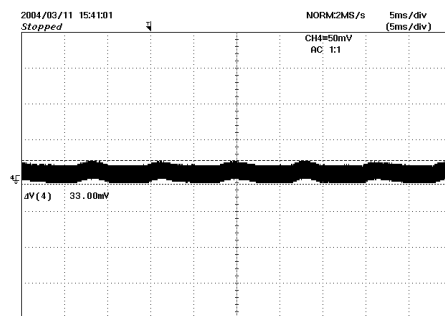


Figure 28 – -5Vsw Ripple, 115 VAC, Peak Load.
5 ms, 20 mV /div

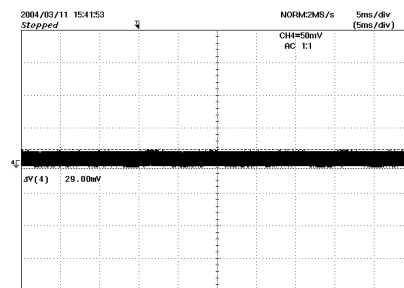


Figure 29 – -5Vsw Ripple, 230 VAC, Peak Load.
5 ms, 20 mV /div



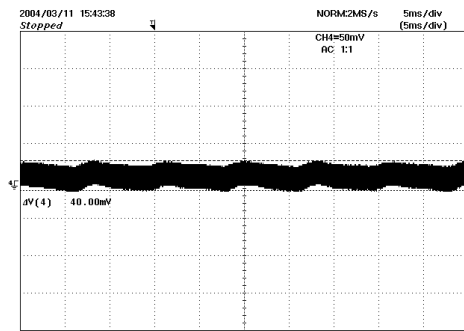


Figure 30 – -5Vsb Ripple, 115 VAC, Peak Load.
5 ms, 50 mV / div

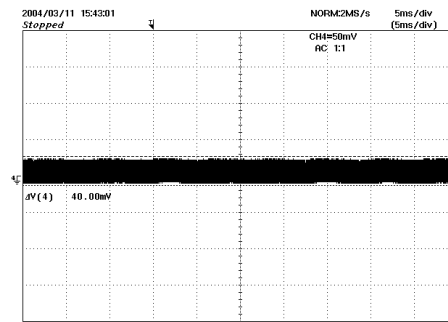


Figure 31 – -5 Vsb Ripple, 230 VAC, Peak Load.
5 ms, 50 mV / div

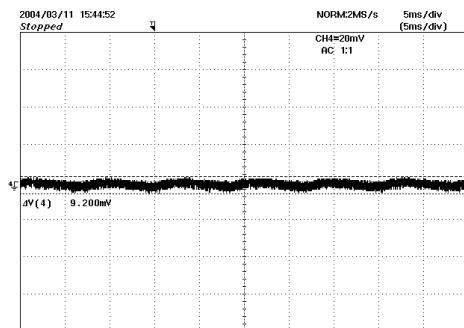


Figure 32 – -22Vsb Ripple, 115 VAC, Peak Load.
5 ms, 20 mV /div

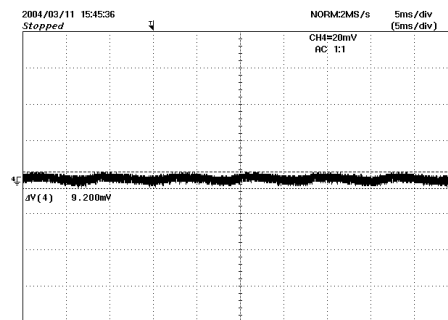


Figure 33 – -22Vsb Ripple, 230 VAC, Peak Load.
5 ms, 20 mV /div

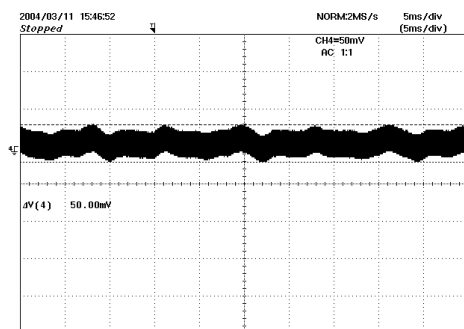


Figure 34 – 33Vsb Ripple, 115 VAC, Peak Load.
5 ms, 50 mV / div

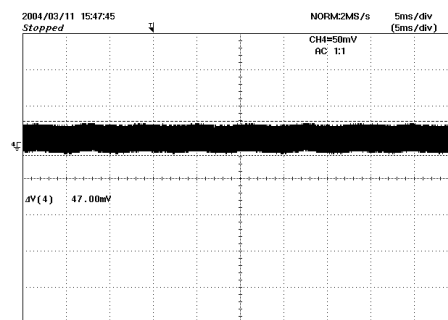


Figure 35 – 33 Vsb Ripple, 230 VAC, Peak Load.
5 ms, 50 mV / div



12 Conducted EMI

EMI was tested at room temperature, at 115 VAC & 230 VAC input, with a resistor load on each output as follows; 3.3V / 1.6 ohms; 5V / 7 ohms; 12V / 31 ohms; -5V / 240 ohms; -22V / 11K ohms; 33V / 16K ohms; VFD / 20 ohms. All plots are **shown with output common connected to the ground of the LISN**, to show worst case results.

12.1 EMI@230V

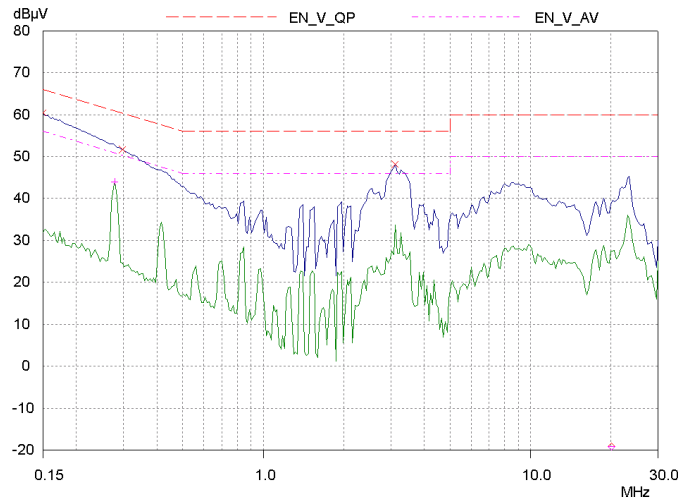


Figure 36 - Conducted EMI, Maximum Steady State Load, LINE: 230 VAC, 60 Hz, and EN55022 B Limits, with output grounded to LISTN

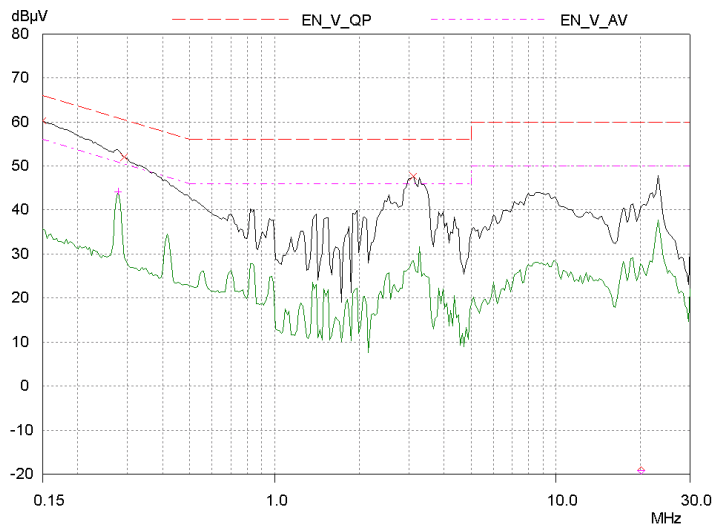


Figure 37 - Conducted EMI, Maximum Steady State Load, NEUTRAL 230 VAC, 60 Hz, and EN55022 B Limits, with output grounded to LISTN



12.2 EMI@115V

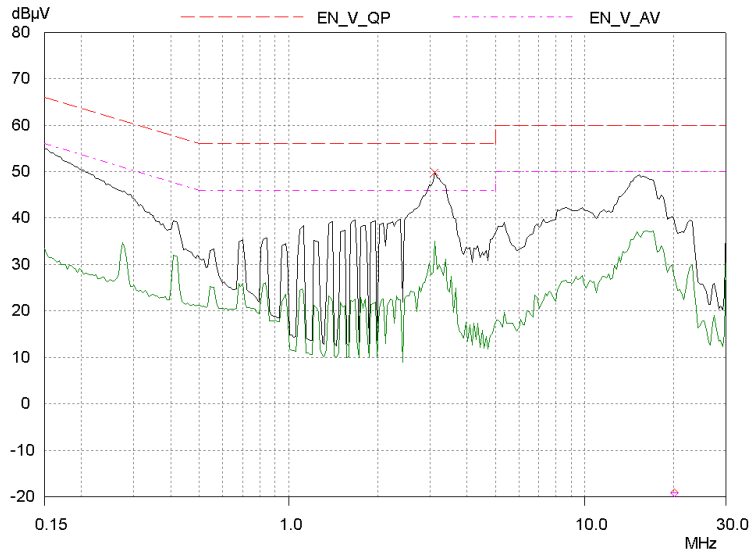


Figure 38 - Conducted EMI, Maximum Steady State Load, LINE: 115 VAC, 60 Hz, and EN55022 B Limits, , with output grounded to LISTN

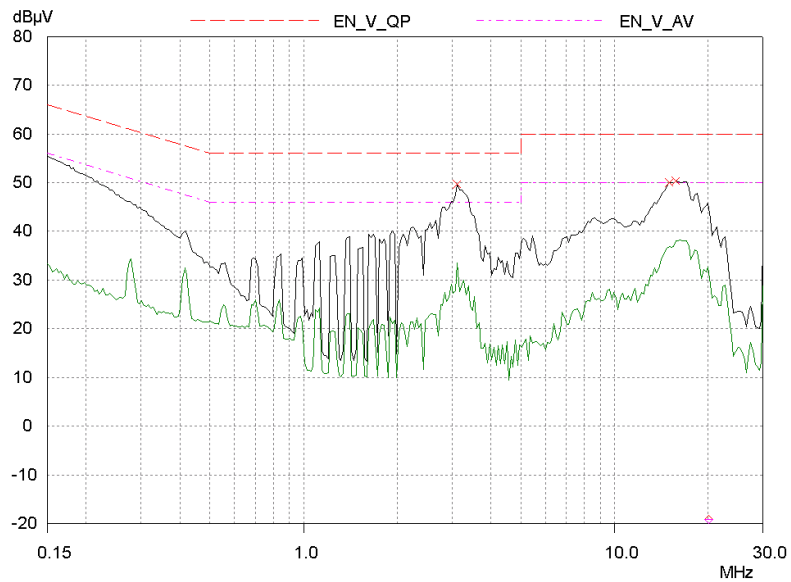


Figure 39 - Conducted EMI, Maximum Steady State Load, NEUTRAL 115 VAC, 60 Hz, and EN55022 B Limits, , with output grounded to LISTN



13 Revision History

| Date | Author | Revision | Description & changes | Reviewed |
|----------------|---------------|-----------------|----------------------------------|-----------------|
| March 30, 2004 | ME | 1.0 | First Release | VC /AM |



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WORLD HEADQUARTERS

Power Integrations
5245 Hellyer Avenue,
San Jose, CA 95138, USA
Main: +1-408-414-9200
Customer Service:
Phone: +1-408-414-9665
Fax: +1-408-414-9765
e-mail:
usasales@powerint.com

AMERICAS

Power Integrations, Inc.
4335 South Lee Street,
Suite G,
Buford, GA 30518, USA
Phone: +1-678-714-6033
Fax: +1-678-714-6012
e-mail:
usasales@powerint.com

CHINA (SHANGHAI)

Power Integrations
International Holdings, Inc.
Rm 807, Pacheer,
Commercial Centre,
555 Nanjing West Road,
Shanghai, 200041, China
Phone: +86-21-6215-5548
Fax: +86-21-6215-2468
e-mail:
chinasales@powerint.com

APPLICATIONS HOTLINE

World Wide +1-408-414-9660

CHINA (SHENZHEN)

Power Integrations
International Holdings, Inc.
Rm# 1705, Bao Hua Bldg.
1016 Hua Qiang Bei Lu,
Shenzhen, Guangdong,
518031, China
Phone: +86-755-8367-5143
Fax: +86-755-8377-9610
e-mail: chinasales@powerint.com

GERMANY

Power Integrations, GmbH
Rueckerstrasse 3,
D-80336, Munich, Germany
Phone: +49-895-527-3910
Fax: +49-895-527-3920
e-mail: eurosales@powerint.com

INDIA (TECHNICAL SUPPORT)

Innovatech
261/A, Ground Floor
7th Main, 17th Cross,
Sadashivanagar
Bangalore, India, 560080
Phone: +91-80-5113-8020
Fax: +91-80-5113-8023
e-mail: indiasales@powerint.com

APPLICATIONS FAX

World Wide +1-408-414-9760

ITALY

Power Integrations s.r.l.
Via Vittorio Veneto 12,
Bresso, Milano,
20091, Italy
Phone: +39-028-928-6001
Fax: +39-028-928-6009
e-mail:
eurosales@powerint.com

JAPAN

Power Integrations, K.K.
Keihin-Tatemono 1st Bldg.
12-20 Shin-Yokohama,
2-Chome,
Kohoku-ku, Yokohama-shi,
Kanagawa 222-0033, Japan
Phone: +81-45-471-1021
Fax: +81-45-471-3717
e-mail:
japansales@powerint.com

KOREA

Power Integrations
International Holdings, Inc.
8th Floor, DongSung Bldg.
17-8 Yoido-dong,
Youngdeungpo-gu,
Seoul, 150-874, Korea
Phone: +82-2-782-2840
Fax: +82-2-782-4427
e-mail:
koreasales@powerint.com

SINGAPORE (ASIA PACIFIC HEADQUARTERS)

Power Integrations, Singapore
51 Newton Road,
#15-08/10 Goldhill Plaza,
Singapore, 308900
Phone: +65-6358-2160
Fax: +65-6358-2015
e-mail:
singaporesales@powerint.com

TAIWAN

Power Integrations
International Holdings, Inc.
17F-3, No. 510,
Chung Hsiao E. Rd., Sec. 5,
Taipei, Taiwan 110, R.O.C.
Phone: +886-2-2727-1221
Fax: +886-2-2727-1223
e-mail:
taiwansales@powerint.com

UK (EUROPE & AFRICA HEADQUARTERS)

1st Floor, St. James's House
East Street
Farnham, Surrey GU9 7TJ
United Kingdom
Phone: +44-1252-730-140
Fax: +44-1252-727-689
e-mail: eurosales@powerint.com

